

KSD401

TV Vertical Deflection Output

- Collector-Base Voltage: V_{CBO}=200V
 Collector Current: I_C=2A
- Collector Dissipation : P_C=25W(T_C=25°C)
- Complement to KSB546



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|--|------------|-------|
| V _{CBO} | Collector-Base Voltage | 200 | V |
| V _{CEO} | Collector-Emitter Voltage | 150 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current | 2 | Α |
| P _C | Collector Dissipation (T _C =25°C) | 25 | W |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | - 55 ~ 150 | °C |

Electrical Characteristics T_C=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C = 500uA, I_E = 0$ | 200 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_C = 10 \text{mA}, I_B = 0$ | 150 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E = -500uA, I_C = 0$ | 5 | | | V |
| I _{CBO} | Collector Cut-off Current | $V_{CB} = 150V, I_{E} = 0$ | | | 50 | μΑ |
| h _{FE} | DC Current Gain | $V_{CE} = 10V, I_{C} = 0.4A$ | 120 | | 400 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | $I_C = 500 \text{mA}, I_B = 50 \text{mA}$ | | | 1 | V |
| f _T | Current Gain Bandwidth Product | $V_{CE} = 10V, I_{C} = 0.4A$ | | 5 | | MHz |

h_{FE} Classification

| Classification | Υ | G |
|-----------------|-----------|-----------|
| h _{FE} | 120 ~ 240 | 200 ~ 400 |

Typical Characteristics

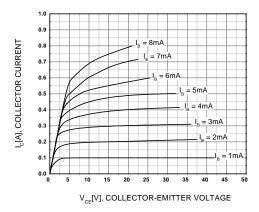


Figure 1. Static Characteristic

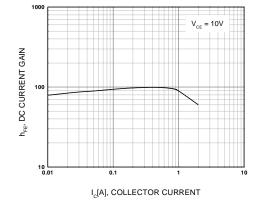


Figure 2. DC current Gain

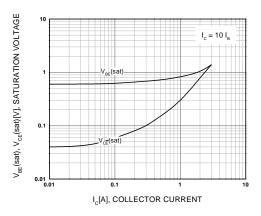


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

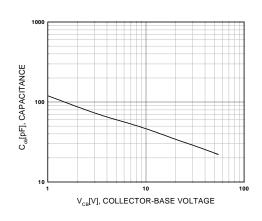


Figure 4. Collector Output Capacitance

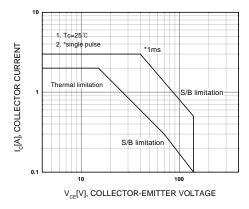


Figure 5. Safe Operating Area

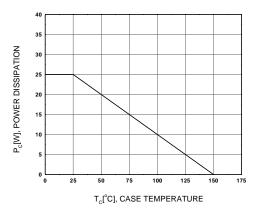
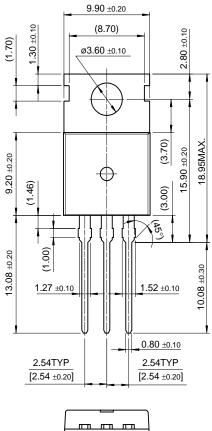


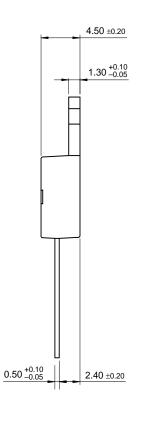
Figure 6. Power Derating

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Package Dimensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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